

# P-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (mΩ) (Typ.)	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)	
- 100	185 at V <sub>GS</sub> = - 10 V	- 3.8	7.9 nC	
	212 at V <sub>GS</sub> = - 4.5 V	- 3.0	7.9110	

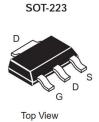
### **FEATURES**

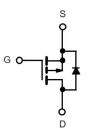
- · DT-Trench Power MOSFET
- 100 % Rg and UIS tested
- · Ultra Low On-Resistance



### **APPLICATIONS**

• Active Clamp Circuits in DC/DC Power Supplies





P-Channel MOSFET

Parameter	Symbol	LIMIT	Unit		
Drain-Source Voltage	V <sub>DS</sub>	- 100			
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a, b</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 3.8		
Continuous Drain Current (1) = 150 °C)	T <sub>A</sub> = 70 °C		- 2.5		
Pulsed Drain Current		I <sub>DM</sub>	- 11	А	
Continuous Source Current (Diode Conduction) <sup>a, b</sup>		I <sub>S</sub>	- 3.8		
Single Pulse Avalanche Current		I <sub>AS</sub>	3.5		
Single Pulse Avalanche Energy	L = 1.0 mH	E <sub>AS</sub>	13	mJ	
	T <sub>C</sub> = 25 °C		2.7		
Maximum Power Dissipation	T <sub>C</sub> = 70 °C	P <sub>D</sub>	1.7	W	
Maximum Fower Dissipation	T <sub>A</sub> = 25 °C		1.55		
	T <sub>A</sub> = 70 °C		0.93		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 5 s	$R_{thJA}$	65	80.5	°C/W	
Maximum Junction-to-Case	Steady State	$R_{thJC}$	30	45		

- a. Surface Mounted on 1" x 1" FR4 board.
- b. Pulse width limited by maximum junction temperature.



Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit	
Static	-			, , , , , , , , , , , , , , , , , , ,			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V, } I_D = -250 \mu\text{A}$	- 100			V	
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1.2		- 2.5	V	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zana Oata Valtana Busin Oursel	I <sub>DSS</sub>	V <sub>DS</sub> =-100V, V <sub>GS</sub> = 0 V			- 1		
Zero Gate Voltage Drain Current		V <sub>DS</sub> = -80V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			- 10	μA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> ≤ -15 V, V <sub>GS</sub> = -10 V	- 3.8			Α	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -0.5 A		185	240	mΩ	
		V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -0.5 A		212	290		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -25 \text{ V}, I_D = -0.5 \text{ A}$		2.2		S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			1250		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -25 \text{ V,V}_{GS} = 0 \text{ V, f} = 1 \text{ MHz}$		50			
Reverse Transfer Capacitance	C <sub>rss</sub>			34			
Total Gate Charge	Qg			7.9		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -50 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -0.5 \text{ A}$		1.6			
Gate-Drain Charge	$Q_{gd}$			2.5			
Gate Resistance	R <sub>g</sub>	f = 1 MHz		10		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			8			
Rise Time	t <sub>r</sub>	$V_{DD} = -50 \text{ V}, I_D = -0.5 \text{ A},$		11		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = -10 \text{ V}, R_g = 6 \Omega$		16			
Fall Time	t <sub>f</sub>			11			
<b>Drain-Source Body Diode Characteristics</b>							
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>A</sub> = 25 °C			-3.8	A	
Pulse Diode Forward Current <sup>a</sup>	I <sub>SM</sub>				-11		
Body Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> = -1 A			-1.2	V	
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	$I_F = -0.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		90		nC	

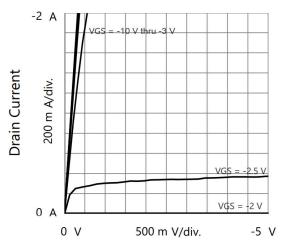
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

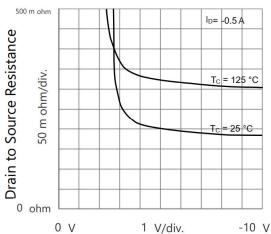


### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

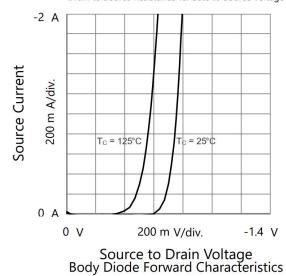
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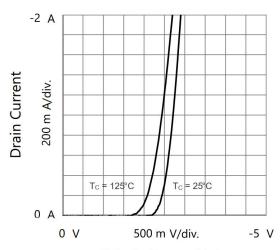


Drain to Source Voltage Output Characteristics

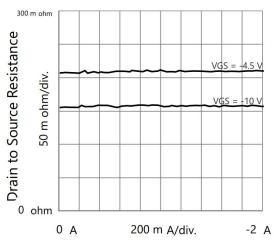


Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage

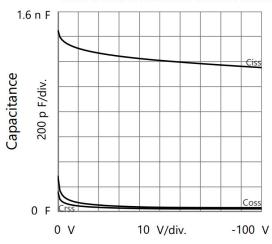




Gate to Source Voltage Transfer Characteristics



Drain Current
Drain to Source Resistance vs. Drain Current

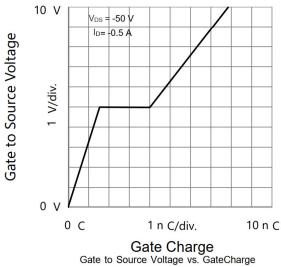


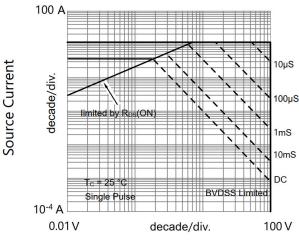
Drain to Source Voltage Capacitances

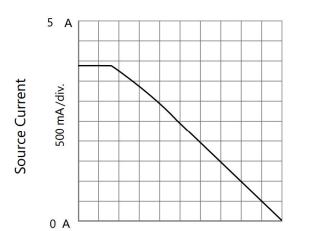




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15 °C/div.

T<sub>C</sub> - Case Temperature

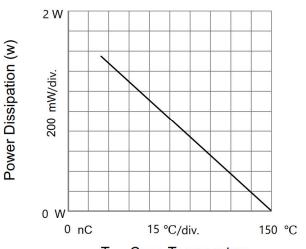
Current Derating

0 nC

Source to Drain Voltage Safe Operating Area, Junction-to-Ambient

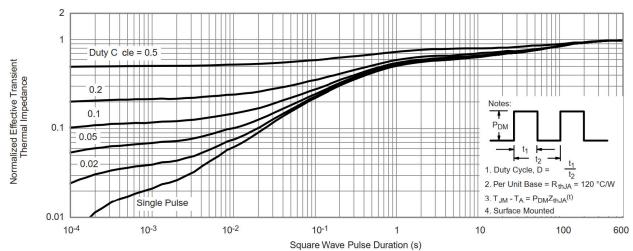


150 °C



T<sub>C</sub> - Case Temperature

Current Derating



Normalized Thermal Transient Impedance, Junction-to-Ambient





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